DUAL J-FET INPUT OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJM2082 is JFET input dual operational amplifiers. The NJM2082 features low input offset and bias current, high input impedance. The NJM2082 ideally suits for fast integrator, DA converter, sample & hold and audio applications. The NJM2082 is improved version of the NJM082.

■ FEATURES

Operating Voltage

 $(\pm 4V \sim \pm 18V)$

High Input Resistance

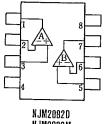
 $(10^{12}\Omega \text{ typ.})$

High Slew Rate Package Outline $(20V/\mu s typ.)$

Bipolar Technology

DIP8, DMP8, SIP8, (SSOP8)

■ PIN CONFIGURATION





■ PACKAGE OUTLINE







NJM2082M



NJM2082V



PIN FUNCITON

1. A OUTPUT

2. A-INPUT

3 . A+INPUT 4 . V-

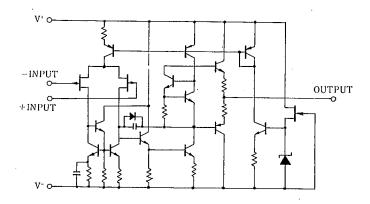
5. B+INPUT

6. B-INPUT

7. B OUTPUT

8. V'

■ EQUIVALENT CIRCUIT (1/2 Shown)



NJM2082L

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER ·	SYMBOL	#18 #30		UNIT	
Supply Voltage	V*/V-			V	
Differential Input Voltage	V _{ID}			V	
Input Voltage	V _{IC}	±15	(note)	٧	
Power Dissipation	PD	(DIP8) 500	(DIP8) 500		
		(DIM8) 300		mW	
	(SIP8) 800 (SSOP8) 250			mW	
			mW		
Operating Temperature Range	Торг	-40~+85		°C	
Storage Temperature Range	T _{stg}	-40~+125		°C	

(note) For supply voltage less than ± 15 V. the absolute maximum input voltage is equal to the supply voltage.

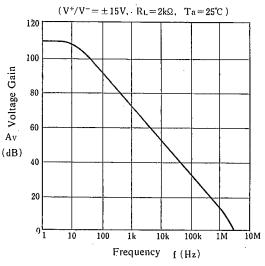
■ ELECTRICAL CHARACTERISTICS

 $(Ta = +25^{\circ}C, V^{+}/V^{-} = \pm 15V)$

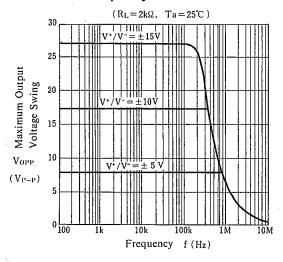
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{10}	$R_S=50\Omega$		2	10	mV
Input Offset Current	I ₁₀		_	5	200	рA
Input Bias Current	IB		_	30	400	pA
Input Resistance	R _{IN}		_	1012		Ω
Large Signal Voltage Gain	Av	$R_L \ge 2k\Omega$, $V_O = \pm 10V$	86	110		dB
Maximum Output Voltage Swing	V _{OM}	$R_L=2k\Omega$	±12	+13.5, -13.0	<u> </u>	v
Input Common Mode Voltage Range	V _{ICM}		±12	+15.0, -12.5		v
Common Mode Rejection Ratio	CMR	R _S ≦10kΩ	70	90		dB
Supply Voltage Rejection Ratio	SVR	R _S ≦10kΩ	76	100	l _	dB
Operating Current	I _{CC}		_	4	6	mA
Slew Rate	SR	•	_	.20		V/μs
Gain Bandwidth Product	GB	f = 10kHz		5		MHz
Equivalent Input Noise Voltage 1	e _n	$R_S = 100\Omega$, $f = 1kHz$	_	13		ถV/√H
Equivalent Input Noise Voltage 2	V _{NI}	RIAA R _S =2.2k Ω , 30kHz LPF	-	1.6		μVrms

■ TYPICAL CHARACTERISTICS

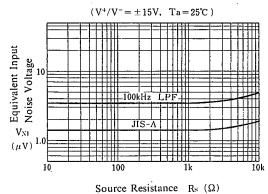
Voltage Gain vs. Frequency



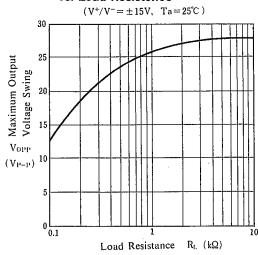
Maximum Output Voltage Swing vs. Frequency



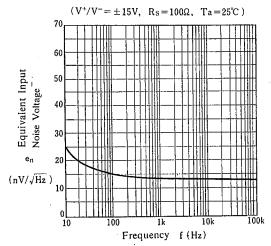
Equivalent Input Noise Voltage vs. Source Resistance



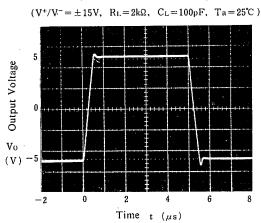
Maximum Output Voltage Swing vs. Load Resistence



Equivalent Input Noise Voltage vs. Frequency



Voltage Follower Palse Response

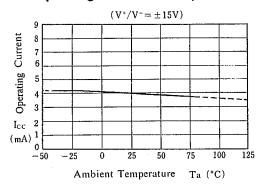


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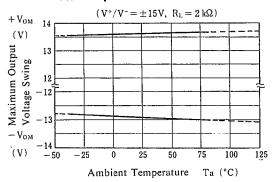
New Japan Radio Co.,Ltd.

TYPICAL CHARACTERISTICS

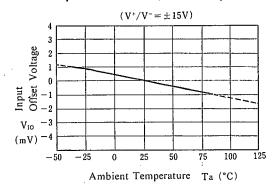
Operating Current vs. Temperature



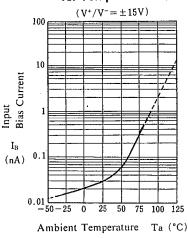
Maximum Output Voltage Swing vs. Temperature



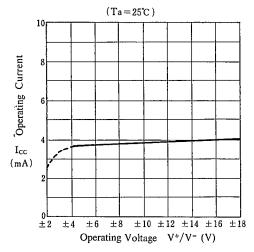
Input Offset Voltage vs. Temperature



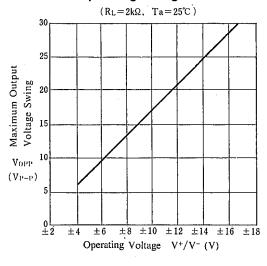
Input Bias Current vs. Temperature



Operating Current vs. Operating Voltage



Maximum Output Voltage Swing vs. Operating Voltage



N.	J	M	7	2	N	8	2
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MEMO

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